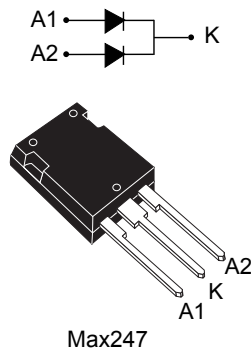


100 V power Schottky rectifier



Features

- High reverse voltage
- Negligible switching losses
- Low forward voltage drop
- Low leakage current
- High temperature
- Low thermal resistance
- Avalanche capability specified
- ECOPACK[®]2 compliant

Applications

- Switching diode
- SMPS
- DC/DC converter
- LED lighting
- Desktop power supply

Description

This dual diode common cathode Schottky rectifier is suited for switched mode power supplies and high frequency DC to DC converters.

Packaged in Max247, the **STPS80H100C** is optimized for use in high frequency computer and telecom converters.

Product status	
STPS80H100C	
Product summary	
$I_{F(AV)}$	2 x 40 A
V_{RRM}	100 V
$T_{j(max.)}$	175 °C
$V_{F(typ.)}$	0.65 V

1 Characteristics

Table 1. Absolute ratings (limiting values, per diode at 25 °C, unless otherwise specified)

Symbol	Parameter	Value	Unit	
V_{RRM}	Repetitive peak reverse voltage	100	V	
$I_{F(RMS)}$	Forward rms current	50	A	
$I_{F(AV)}$	Average forward current, $\delta = 0.5$, square wave	$T_C = 150\text{ °C}$ Per diode	40	A
		$T_C = 140\text{ °C}$ Per device	80	
I_{FSM}	Surge non repetitive forward current	$t_p = 10\text{ ms}$ sinusoidal	400	A
P_{ARM}	Repetitive peak avalanche power	$t_p = 10\text{ }\mu\text{s}$, $T_j = 125\text{ °C}$	2822	W
T_{stg}	Storage temperature range	-65 to +175	°C	
T_j	Maximum operating junction temperature ⁽¹⁾	+175	°C	

1. $(dP_{tot}/dT_j) < (1/R_{th(j-a)})$ condition to avoid thermal runaway for a diode on its own heatsink.

Table 2. Thermal resistance parameters

Symbol	Parameter	Max. value	Unit	
$R_{th(j-c)}$	Junction to case	Per diode	0.7	°C/W
		Total	0.5	
$R_{th(c)}$	Coupling	0.3	°C/W	

When the diodes 1 and 2 are used simultaneously:

$$\Delta T_j(\text{diode1}) = P_{(\text{diode1})} \times R_{th(j-c)} (\text{per diode}) + P_{(\text{diode2})} \times R_{th(c)}$$

For more information, please refer to the following application note:

- AN5088 : Rectifiers thermal management, handling and mounting recommendations

Table 3. Static electrical characteristics (per diode)

Symbol	Parameter	Test conditions	Min.	Typ.	Max.	Unit	
$I_R^{(1)}$	Reverse leakage current	$T_j = 25\text{ °C}$	$V_R = V_{RRM}$	-		20	μA
		$T_j = 125\text{ °C}$		-	7	20	mA
$V_F^{(2)}$	Forward voltage drop	$T_j = 25\text{ °C}$	$I_F = 40\text{ A}$	-		0.80	V
		$T_j = 125\text{ °C}$		-	0.65	0.70	
		$T_j = 25\text{ °C}$	$I_F = 80\text{ A}$	-		0.94	
		$T_j = 125\text{ °C}$		-	0.79	0.84	

1. Pulse test: $t_p = 5\text{ ms}$, $\delta < 2\%$

2. Pulse test: $t_p = 380\text{ }\mu\text{s}$, $\delta < 2\%$

To evaluate the conduction losses, use the following equation: $P = 0.56 \times I_{F(AV)} + 0.0035 \times I_F^2 (RMS)$

For more information, please refer to the following application notes related to the power losses :

- AN604: Calculation of conduction losses in a power rectifier
- AN4021: Calculation of reverse losses on a power diode

1.1 Characteristics (curves)

Figure 1. Average forward power dissipation versus average forward current (per diode)

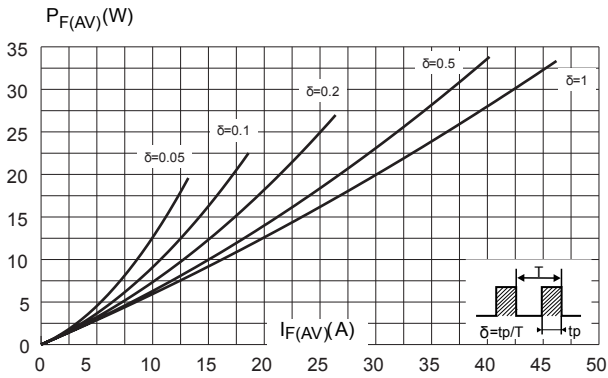


Figure 2. Average forward current versus ambient temperature ($\delta = 0.5$, per diode)

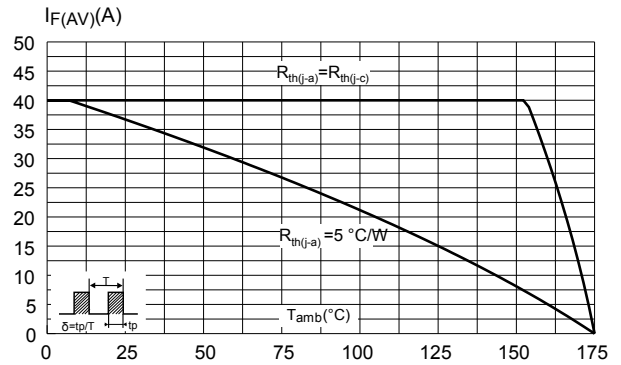


Figure 3. Normalized avalanche power derating versus pulse duration ($T_j = 125$ °C)

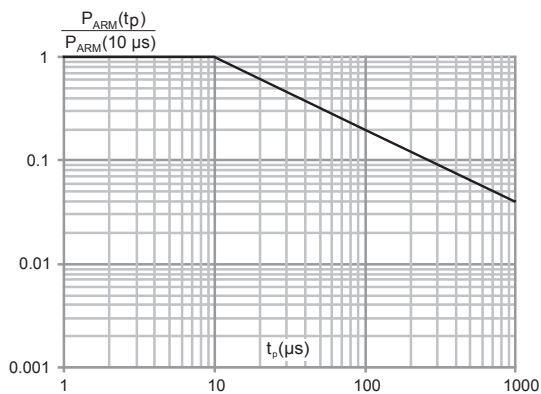


Figure 4. Relative variation of thermal impedance junction to case versus pulse duration

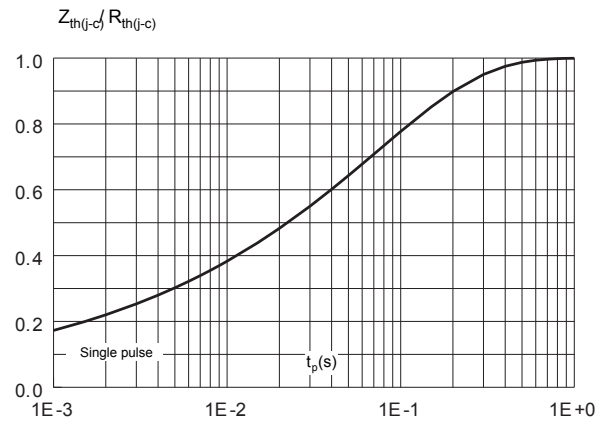


Figure 5. Reverse leakage current versus reverse voltage applied (typical values, per diode)

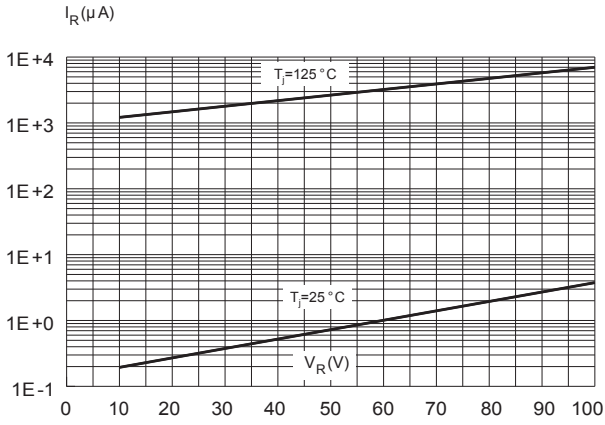


Figure 6. Junction capacitance versus reverse voltage applied (typical values, per diode)

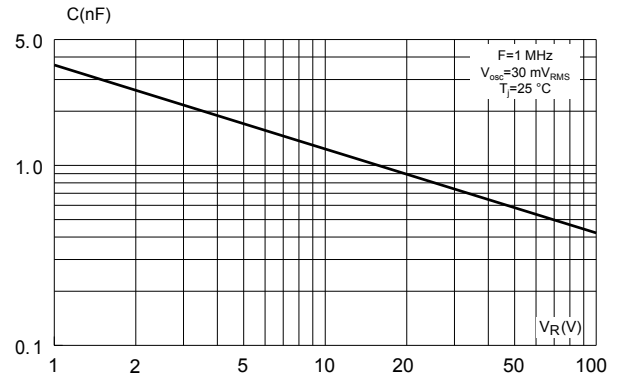
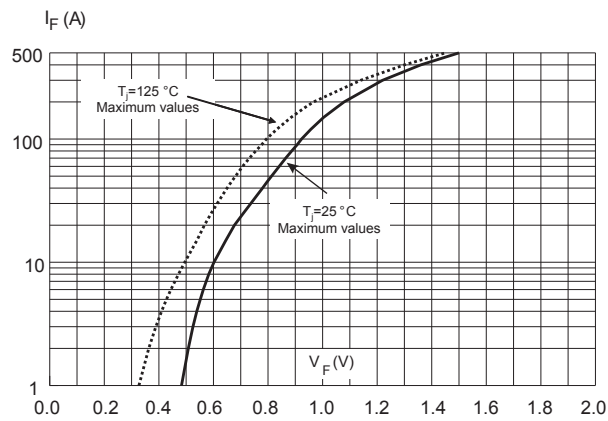


Figure 7. Forward voltage drop versus forward current (maximum values, per diode)



2 Package information

In order to meet environmental requirements, ST offers these devices in different grades of ECOPACK® packages, depending on their level of environmental compliance. ECOPACK® specifications, grade definitions and product status are available at: www.st.com. ECOPACK® is an ST trademark.

2.1 Max247 package information

- Epoxy meets UL94, V0
- Cooling method: by conduction (C)

Figure 8. Max247 package outline

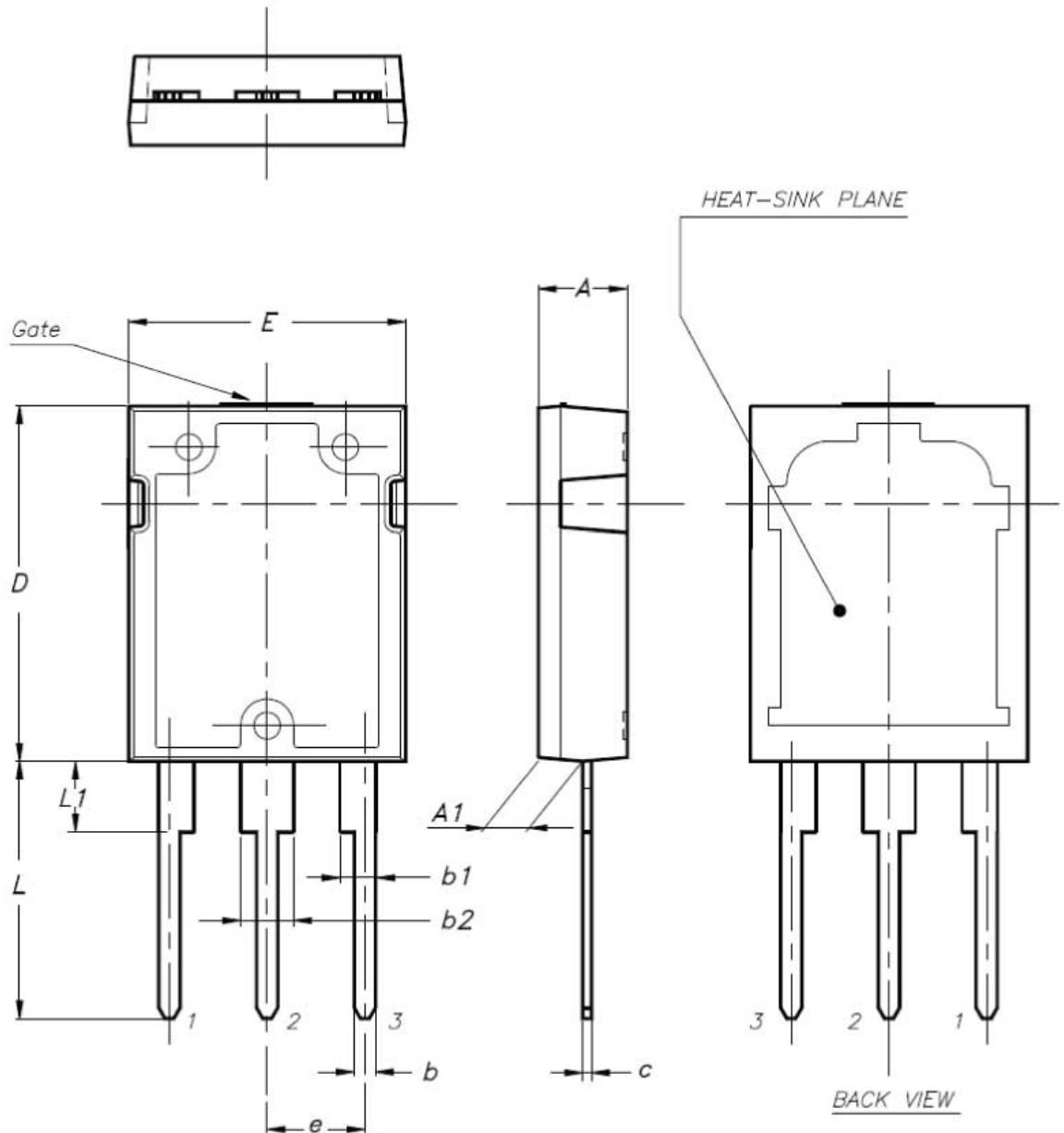


Table 4. Max247 package mechanical data

Ref.	Dimensions			
	Millimeters		Inches (for reference only)	
	Min.	Max.	Min.	Max.
A	4.70	5.30	0.185	0.208
A1	2.20	2.60	0.086	0.102
b	1.00	1.40	0.039	0.055
b1	2.00	2.40	0.078	0.094
b2	3.0	3.40	0.118	0.133
c	0.40	0.80	0.015	0.031
D	19.70	20.30	0.775	0.800
E	15.30	15.90	0.602	0.626
e	5.35	5.55	0.210	0.218
L	14.20	15.20	0.559	0.598
L1	3.70	4.30	0.145	0.169

3 Ordering information

Table 5. Order code

Order code	Marking	Package	Weight	Base qty.	Delivery mode
STPS80H100CY	STPS80H100CY	Max247	4.90 g	30	Tube

Revision history

Table 6. Document revision history

Date	Revision	Changes
July-2003	2B	Last release.
21-Jun-2010	3	Updated package illustration on page 1 and Section 2: Package information on page 5.
02-Jul-2018	4	Updated Figure 3 . Normalized avalanche power derating versus pulse duration ($T_j = 125\text{ °C}$) and Table 1 . Absolute ratings (limiting values, per diode at 25 °C, unless otherwise specified).

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